

LiNbO₃, MgO:LiNbO₃ and Fe:LiNbO₃

LiNbO₃ Crystal is widely used as frequency doublers for wavelength > 1μm and optical parametric oscillators (OPOs) pumped at 1064 nm as well as quasi-phase-matched (QPM) devices. Due to its large Electro-Optic (E-O) and Acousto-Optic (A-O) coefficients, LiNbO₃ crystal is the most commonly used material for Pockel Cells, Q-switches and phase modulators, waveguide substrate, and surface acoustic wave (SAW) wafers, etc.



I. Pure Lithium Niobate (LiNbO₃)

AOTK provides high quality and large size LiNbO₃ crystals for laser frequency doublers, OPOs and quasi-phase-matched doublers, as well as waveguide substrate and SAW wafers. High quality LiNbO₃ components with aperture of (2 - 15) x (2 - 15) mm² and length up to 50 mm for frequency doublers and optical parametric oscillators (OPOs), 50x50x1 mm³ or Dia. 3" x 1 mm LiNbO₃ substrate for waveguide optics, and Dia. 3" & Dia. 4" SAW wafers are available with high volume and at low price.

Basic Properties

1. Structural and Physical Properties

Crystal Structure	Trigonal, point group 3m
Lattice Parameters	a = 5.148Å, c = 13.863Å
Density	4.64 g/cm ³
Mohs Hardness	5
Melting Point	1250°C
Curie Point	1160°C
Thermal Expansion Coefficient	$\alpha_1 = \alpha_2 = 2 \times 10^{-6}/^{\circ}\text{C}$, $\alpha_3 = 2.2 \times 10^{-6}/^{\circ}\text{C}$ at 25°C
Thermal Conductivity	38 W/m/K at 25°C
Elastic Stiffness Constant	$C_{11}^E = 2.04 \times 10^{11}$ N/m ² , $C_{33}^E = 2.46 \times 10^{11}$ N/m ²
Piezoelectric Strain Constant	$d_{22} = 2.04 \times 10^{-11}$ C/N, $d_{33} = 19.22 \times 10^{-11}$ C/N
Dielectric Constant	$\epsilon_{11}/\epsilon_0 = 85$, $\epsilon_{33}/\epsilon_0 = 29.5$
Absorption Coefficient	~ 0.1%/cm @1064 nm

2. Linear Optical Properties

Transparency Region	420-5200nm
Refractive Indexes	
at 1300 nm	$n_e = 2.146$, $n_o = 2.220$
at 1064 nm	$n_e = 2.156$, $n_o = 2.320$
at 632.8 nm	$n_e = 2.203$, $n_o = 2.286$
Sellmeier Equations (λ in μm)	$n_o^2 = 4.9048 + 0.11768/(\lambda^2 - 0.0475) - 0.027169\lambda^2$ $n_e^2 = 4.5820 + 0.099169/(\lambda^2 - 0.04443) - 0.02195\lambda^2$
Optical Homogeneity	~ 5 x 10 ⁻⁵ /cm

3. NonLinear Optical Properties

NLO Coefficients	$d_{33} = 34.4$ pm/v $d_{31} = d_{15} = 5.95$ pm/v $d_{22} = 3.07$ pm/v
------------------	---

Effective NLO Coefficients	$d_{\text{eff}} = 5.7 \text{ pm/V}$ or $\sim 14.6 \times d_{36}$ (KDP) for frequency doubling 1300 nm $d_{\text{eff}} = 5.3 \text{ pm/V}$ or $\sim 13.6 \times d_{36}$ (KDP) for OPO pumped at 1064 nm $d_{\text{eff}} = 17.6 \text{ pm/V}$ or $\sim 45.0 \times d_{36}$ (KDP) for quasi-phase-matched structure
Electro-Optic Coefficients	$\gamma_{33}^T = 32 \text{ pm/V}$, $\gamma_{33}^S = 31 \text{ pm/V}$ $\gamma_{31}^T = 10 \text{ pm/V}$, $\gamma_{31}^S = 8.6 \text{ pm/V}$ $\gamma_{22}^T = 6.8 \text{ pm/V}$, $\gamma_{22}^S = 3.4 \text{ pm/V}$
Half-Wave Voltage, DC	
Electrical field z, light \perp z:	3.03 KV
Electrical field x or y, light z:	4.02 KV
Optical Damage Threshold	> 200MW/cm ² (@ 1064nm, 10ns, 10Hz)

Main Applications

I. Applications for Q-switch Elements

LiNbO₃ is extensively used as electro-optic modulator and Q-switch for Nd:YAG, Nd:YLF and Ti:Sapphire lasers as well as modulator for fiber optics, etc. The transverse modulation is mostly employed for LiNbO₃. If a LiNbO₃ crystal is used as Q-switch crystal, the light propagates in Z-axis and electric field applies to X-axis, the refractive retardation will be $\Gamma = \pi L n_0^3 \gamma_{22} V / \lambda d$. MgO:LiNbO₃ and ZnO:LiNbO₃ crystals have similar electro-optic properties to LiNbO₃ but with higher damage threshold. The specifications of LiNbO₃ Q-Switch Elements listed as the following table:

Standard Specifications

Standard Dimension	9x9x25 or 10x10x20mm ³
Dimensional Tolerance	(W \pm 0.1mm) x (H \pm 0.1mm) x (L +0.2/-0.1 mm)
Wavefront Distortion	< $\lambda/4$ @633 nm
Angle Tolerance	$\Delta\theta < \pm 0.2^\circ$, $\Delta\phi < \pm 0.2^\circ$
Flatness	$\lambda/8$ @633 nm
Surface Quality	10/5 Scratch/Dig per MIL-O-13830A
Parallelism	< 20 arc seconds
Perpendicularity	< 5 arc minutes
Clear Aperture	> 90% central area
AR Coating	R < 0.2% @1064nm per surface
Electrodes	Au or Cr electrode on both X-surfaces
Quality Warranty Period	one year under proper use

II. Surface Acoustic Wave (SAW) Devices

LiNbO₃ crystal is widely applied as an excellent acousto-optic material for surface acoustic wave (SAW) devices (such as filters, oscillators and resonators) and ultrasonic transducer due to its high electro-mechanical coupling factor, low acoustic transmission loss, stable physical and chemical properties.

AOTK supplies large quantities of LiNbO₃ boules, as-cut or finished $\phi 3"$ and $\phi 4"$ wafers available up to 20,000 pieces per month with good quality and very low price.

Typical Applications of Piezoelectronic LiNbO₃

- Surface Acoustic Wave (SAW) Device
- Bulk Acoustic Wave (BAW) Device
- Leaky Surface Acoustic Wave (LBAW) Device
- Piezoelectric Transducer (PET)
- Piezoelectric Sensor (PES)



Typical Properties of Piezoelectric LiNbO₃

Orientation	127.86° Y-cut	Y-cut
SAW Velocity	3970 m/s	3485 m/s
Electromechanical Coupling Factor	$K_s^2 = 5.5\%$	$K_s^2 = 4.3\%$
Temperature Coefficients of Delay (TCD)	$78 \times 10^{-6}/^\circ\text{C}$	$95 \times 10^{-6}/^\circ\text{C}$
Temperature Coefficients of Velocity (TCV)	$-60 \times 10^{-6}/^\circ\text{C}$	$-80 \times 10^{-6}/^\circ\text{C}$

Specifications of LiNbO₃ SAW Wafer

Type Specifications	Boule		Wafer	
Diameter	Φ3"	Φ4"	Φ3"	Φ4"
Length or Thickness (mm)	≤100	≤50	0.35-1.0	
Orientation	127.86° Y, 64° Y, 135° Y, X, Y, Z, and other cut			
Ref. Flat Orientation	X, Y			
Ref. Flat Length	22±2mm	32±2mm	22±2mm	32±2mm
Front Side Polishing	Mirror polished 5-15 Å			
Back Side Lapping	0.3-1.0 μm			
Flatness (μm)	< 15			
Bow (μm)	< 25			

Note:

- I. Other dimension is also available upon request.
- II. Wafers are packaged in plastic containers (25 pieces wafers each).

III. Waveguide Substrates

LiNbO₃ crystal is the mostly used inorganic substrate for electro-optic waveguide applications.

Specifications of LiNbO₃ Waveguide Substrates

Standard Dimension	1) 50x50x1 mm ³ for X-cut, Y-cut, or Z-cut 2) Φ3"x1 mm ³ for Y-cut or Z-cut 3) Other dimension is available upon request
Orientation Tolerance	< 10'
Surfaces Finish	One surface polished to better than $\lambda/2$ (with mount) and free from surface defects when observed by a 50X microscope, the other face fine ground

II. Magnesium Oxide Doped Lithium Niobate (MgO:LiNbO₃)

MgO:LiNbO₃ crystal is widely used for high power frequency doubling (SHG), mixing (SFG) and optical parametric oscillator (OPO). MgO:LiNbO₃ has similar effective nonlinear coefficients as pure LiNbO₃. But it has the advantages such as high damage threshold (over 300MW/cm² @ 1064 nm, 12ns), noncritical phase matching (NCPM) at room temperature, excellent E-O and NLO properties, good mechanical and chemical properties compared with pure LiNbO₃.

Its Sellmeier equations (7 mol% MgO doping) are:

$$n_o^2 = 4.8762 + 0.115540/(\lambda^2 - 0.04674) - 0.033119\lambda^2 \quad (\lambda \text{ in } \mu\text{m})$$

$$n_e^2 = 4.5469 + 0.094779/(\lambda^2 - 0.04439) - 0.026721\lambda^2$$

Over 45% and 60% of SHG efficient are obtained in pulsed and cw Nd:YAG lasers respectively, by angle tuned phase matchable SHG of Nd:YAG laser (1064 nm) and NCPM SHG of laser lasers (1053 nm) of MgO:LiNbO₃ at room temperature. MgO:LiNbO₃ is also a good crystal for high power quasi-phase-matched waveguide structure for doubler, optical parametric oscillator (OPO) and amplifier (OPA).

AOTK supplies the typical sizes of MgO:LiNbO₃ crystals - 5x5x(20-30) mm³ for OPO and frequency doubler, (20-25)x(20-25)x1 mm³ for waveguide substrates. Other sizes and AR or HR-coatings are available upon request.

III. Iron Doped Lithium Niobate (Fe:LiNbO₃)

Fe:LiNbO₃ is an excellent photorefractive crystal with high electro-optic coefficients, high photorefractive sensitivity and diffraction efficiency without applied electric field. Therefore, Fe:LiNbO₃ crystal will find suitable applications in phase conjugation and holographic recording. High quality Fe:LiNbO₃ crystal, with size as large as ϕ 3" and iron doped concentrations from 0.01 to 0.1 atm%, could be supplied by AOTK. Some special fabrications are also available to meet customers' requirements.

All statements, technical information and recommendations related to the products herein are based upon information believed to be reliable or accuracy or completeness thereof is not guaranteed, and no responsibility is assumed for any inaccuracies. The user assumes all risks and liability whatsoever in connection with the use of a product or its application, AOTK reserves the right to change at any time of a product offered for sale herein. AOTK makes no representations that the products herein are free from any intellectual property claims of others. Please contact AOTK for more information.